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# Study of Metal Chalcogenide Material for Optical and Electrical Properties

Soham Biswas, Dr. Surbhi Malik

***Abstract: Metal chalcogenide materials offer a complex tapestry of optical and electrical properties that engage researchers from a variety of disciplines, making their study an important area of study in materials science. This abstract light up the dual nature of these materials and their possible uses by exploring the complex interactions that exist between structure, composition, and functioning. The search for new materials with customised optical responses has focused attention on the optical characteristics of metal chalcogenides recently. Optoelectronic device improvements are made possible by the versatile platform provided by the bandgap engineering in these compounds for altering light-matter interactions. A thorough understanding of metal chalcogenides' optical properties is provided by examining their absorption and emission spectra, quantum yield, and nonlinear optical behaviours. This knowledge is essential for the creation of sensors, photodetectors, and light-emitting gadgets of the future. Concurrently, the investigation of electrical characteristics in metal chalcogenides reveals a multifaceted environment controlled by elements such doping effects, conductivity, and charge carrier mobility. Optimising the performance of electronic devices relies heavily on the synergy between structural elements and electronic function. Solving problems concerning defect conductivity and charge transport methods can help improve the efficiency of solar cells, thermoelectric devices, and metal chalcogenide transistors. Moreover, metal chalcogenides' coexistence of distinct optical and electrical properties creates opportunities for multipurpose uses. There is potential for breakthroughs in industries like wearable technology, energy harvesting, and telecommunications if these materials are used to create integrated devices that seamlessly connect optical sensing with electronic functioning. The abstract highlights the importance of adopting a comprehensive approach in order to understand the many features of metal chalcogenides. Researchers can fully use these materials by investigating both their optical and electrical aspects at the same time. This will allow for the development and application of innovative technologies that take advantage of these materials' special qualities. In addition to advancing basic materials science, the study of metal chalcogenides sheds light on how optical and electrical properties can eventually combine in previously unheard-of ways, spurring technological advancement.***

## I. INTRODUCTION

The complex interplay between the optical and electrical properties of metal chalcogenide materials has made their investigation fascinating in the field of materials science. Sulphur, selenium, and tellurium are examples of the chalcogenide anions that combine uniquely with metal cations to form a unique class of compounds with exceptional properties that are in high demand for a wide range of applications. This introduction emphasises the importance of comprehending both the optical and electrical properties of metal chalcogenides, setting the basis for the thorough study of these materials.

The tunable electronic bandgaps of metal chalcogenides have attracted a lot of interest because they provide a flexible platform for adjusting optical responses. These materials are attractive options for the creation of cutting-edge optoelectronic devices because of their capacity to control absorption and emission spectra and their investigation of nonlinear optical behaviours. Scientists investigate the nuances of these optical characteristics in an effort to maximise the potential of metal chalcogenides for the development of effective sensors, photodetectors, and light-emitting devices.

Concurrently, the examination of metal chalcogenides' electrical characteristics reveals a multifaceted terrain that impacts their functionality in electronic apparatuses. The optimisation of transistor, solar cell, and thermoelectric device functionality is largely dependent on charge carrier mobility, conductivity, and the effects of doping. To improve the overall effectiveness of these electronic components and overcome obstacles pertaining to charge transport methods, it is imperative to comprehend the interaction between structure and electronic behaviour. The convergence of optical and electrical properties in metal chalcogenide materials is the main objective of this investigation. Through the integration of these aspects, scientists want to fully realise the promise of these compounds, imagining a time when multifunctional devices will smoothly blend electronic and optical sensing capabilities. Beyond basic materials science, metal chalcogenides have a revolutionary effect that drives technological advancement towards new uses in industries like wearables, sustainable energy, and telecommunications.

## II. SYNTHESIS AND PREPARATION METHODS

A crucial area of materials research is the synthesis and processing of metal chalcogenide materials, which affects their electrical, optical, and structural characteristics. To fully utilise metal chalcogenides in a variety of applications, such as energy harvesting and optoelectronics, these features must be able to be tailored. This thorough review delves into the many methods used to create metal chalcogenide materials, with a focus on experimental methods for manipulating their characteristics.

### A. Techniques for Generating Metal Chalcogenide Materials

1) *Chemical Precipitation:* One commonly used technique for creating metal chalcogenide nanoparticles is chemical precipitation. This method forms the desired metal chalcogenide by mixing metal salts and chalcogen precursors in a solvent and starting a chemical reaction. The size, shape, and crystallinity of the resultant nanoparticles are greatly influenced by the solvent, temperature, and reaction time selections. This method offers a rather easy and economical way to create a range of metal chalcogenides with specific characteristics.
2) *Hydrothermal and Solvothermal Synthesis:* High-pressure, high-temperature environments are used in hydrothermal and solvothermal processes to encourage the crystallisation of metal chalcogenides. Particle size, shape, and phase composition can all be precisely controlled by researchers by carefully adjusting the reaction parameters. Water is used as the solvent in hydrothermal synthesis, which is particularly appealing because to its eco-friendliness. Conversely, solvothermal synthesis uses organic solvents and can produce a wider variety of metal chalcogenide compounds.
3) *Template Assisted Synthesis:* Template-assisted synthesis is based on directing the creation of metal chalcogenide structures using templates or scaffolds. Organic polymers, inorganic substances, and even living things can serve as templates. The creation of distinct nanostructures, including nanowires, nanotubes, and nanoparticles, is made possible by this method. The template acts as a scaffold to enable the precise control of the size and morphology of metal chalcogenides during their controlled growth.
4) *Sol-Gel Method:* Using the sol-gel process, a metal alkoxide precursor is transformed into a sol, which is then gelated and heated to produce the metal chalcogenide. This method provides a flexible way to create coatings, thin films, and nanoparticles. The final material's properties can be precisely tuned thanks to the controllable precursor concentration, processing temperature, and conditions. Large-scale production and the creation of thin films for electronic applications are two areas where sol-gel synthesis excels.
5) *Chemical Vapour Deposition (CVD):* Chemical Vapour Deposition is a gas-phase synthesis technique wherein metal chalcogenide thin films are formed on a substrate by breaking down precursor vapours. Excellent control over layer thickness, homogeneity, and crystallinity is provided by CVD. Researchers can modify temperature, pressure, and precursor flow rates to customise the composition and characteristics of the films that are deposited. For the synthesis of metal chalcogenide films used in semiconductor device applications, this method is very beneficial.

### B. Methods for Controlling Properties via Experimentation

1) *Doping and Alloying:* To alter the electrical characteristics of metal chalcogenides, doping entails introducing impurities into their crystal lattice. Bandgap, carrier mobility, and conductivity can all be tailored with the help of this method. Conversely, alloying is the process of mixing several metal chalcogenides to produce materials with improved or distinct qualities. Researchers can adjust the optical and electrical properties of the final materials by carefully adding dopants or alloying elements during synthesis.
2) *Controlled Growth Conditions:* The growth conditions during synthesis have a significant impact on the characteristics of metal chalcogenides. The temperature, pressure, reaction time, and concentrations of precursors are important factors that affect the size, shape, and crystallinity of the materials that are synthesised. Adjusting these parameters enables the management of structural flaws, grain boundaries, and additional elements impacting the general functionality of metal chalcogenide materials in optoelectronic apparatuses.
3) *Post Synthesis Treatments:* Metal chalcogenides can have their characteristics optimised by using post-synthesis procedures such as annealing, sintering, and surface modification. Improvements in overall material stability, fault removal, and crystallinity can all be achieved by annealing methods. Enhanced electrical conductivity and denser formations can be achieved through sintering. It is possible to manipulate the surface properties and affect how a material interacts with other materials or environments by using surface modification techniques like chemical functionalization or ligand exchange.

4) *Size and Morphology Control:* The optical and electrical properties of metal chalcogenide nanoparticles are highly dependent on their size and shape. Particle size and shape can be controlled using a variety of synthetic techniques, including as seed-mediated growth, template-assisted synthesis, and surfactant-assisted techniques. In nanoscale materials, size-dependent quantum effects become increasingly prominent and influence their bandgap and optical properties. In order to customise materials for particular purposes, control over these variables is crucial.
5) *Hybrid Material Formation:* Enhanced functionality can be obtained by mixing metal chalcogenides with other materials such as polymers, carbon-based compounds, or metal oxides to create hybrid materials. The mechanical strength, flexibility, and compatibility with various substrates can all be enhanced through hybridization. Through meticulous selection of secondary components and their incorporation either during or after synthesis, researchers can create composites with customised properties fit for a wide range of applications.

## III. CHARACTERIZATION TECHNIQUES

To understand the behaviour of metal chalcogenide materials and optimise their performance for different applications, it is essential to characterise their structural, optical, and electrical properties. A thorough examination of important characterisation methods is given in this part, including optical spectroscopy, electrical characterization techniques, scanning electron microscopy (SEM), and X-ray diffraction (XRD).

### A. X-Ray Diffraction (XRD)

One essential method for clarifying the crystalline structure of metal chalcogenide materials is X-ray diffraction. A material can be exposed to X-rays, and the diffraction pattern that is produced can be used to determine how the atoms are arranged in the crystal lattice. X-ray diffraction (XRD) is a useful technique in the study of metal chalcogenides because it can be used to determine lattice constants, grain sizes, and the presence of specific crystal phases.

Phase identification is usually possible due to the unique peaks in the XRD pattern that correspond to particular crystallographic planes. Diffraction pattern analysis is done using Bragg's Law, which connects the incidence angle of X-rays to the crystal plane spacing. X-ray diffraction (XRD) data is used by researchers to verify the creation of desired phases, find impurities, and evaluate how synthesis circumstances affect crystal quality.

### B. Scanning Electron Microscopy (SEM)

When examining the morphology and surface characteristics of metal chalcogenide materials at the micro- to nanoscale, scanning electron microscopy is an effective method. SEM creates high-resolution pictures by scanning the sample surface with a concentrated electron beam. This method offers important information about the shape, size distribution, and presence or absence of flaws or agglomerates in the particles.

Additionally, for elemental analysis, SEM can be combined with energy-dispersive X-ray spectroscopy (EDS). EDS helps characterise metal chalcogenides with complicated compositions by enabling researchers to determine the elemental composition of distinct locations within a sample.

### C. Optical Spectroscopy

Optical spectroscopy provides important insights into the optical properties of metal chalcogenide materials through a variety of techniques such as photoluminescence spectroscopy, Raman spectroscopy, and UV-Vis absorption spectroscopy.

1) *UV-Vis Absorption Spectroscopy:* UV-Vis absorption spectroscopy is used to evaluate how light is absorbed by metal chalcogenides in both the visible and ultraviolet spectrums. By obtaining knowledge about the bandgap energy from the absorption spectrum, scientists can evaluate the optical characteristics of the materials and comprehend electronic transitions.
2) *Photoluminescence Spectroscopy:* In photoluminescence spectroscopy, photons released from a sample are measured after it is exposed to light. This method sheds light on the material's emission characteristics, such as phosphorescence and fluorescence. Photoluminescence is a popular tool for studying quantum confinement effects, exciton dynamics, and defect states in metal chalcogenides.
3) *Raman Spectroscopy:* A material's vibrational modes can be fingerprinted using Raman spectroscopy, which offers information about the material's molecular and crystal structures. Raman spectroscopy is useful in metal chalcogenides to identify phase transitions, lattice vibrations, and structural flaws.

### *D. Electrical Characterization Methods*

For metal chalcogenide materials to be used in electronic devices, it is essential to comprehend their electrical characteristics. Numerous methods of electrical characterisation, including impedance spectroscopy, conductivity tests, and Hall effect measurements, offer important insights into the mechanisms behind charge transport and carrier mobility.

1) *Conductivity Measurements:* Measurements of conductivity evaluate a material's capacity to conduct electrical charge. The conductivity of metal chalcogenides is affected by crystalline structure, flaws, and doping. In order to determine the conductivity of thin films or bulk materials, four-point probe sets are frequently employed to measure the resistivity of certain materials.
2) *Hall Effect Measurements:* The carrier concentration, mobility, and type (electrons or holes) in a semiconductor are all revealed via Hall effect measurements. A Hall voltage is produced by applying a magnetic field perpendicular to the current flow. This voltage is proportional to the properties of the charge carriers. This method is very helpful in figuring out how charge carriers behave in metal chalcogenides.
3) *Impedance Spectroscopy:* Impedance spectroscopy is a flexible method that can be used to investigate a material's electrical characteristics at various frequencies. Impedance spectroscopy can provide details on resistive elements, capacitance, and charge transport in metal chalcogenides. Researchers are able to fully comprehend the electrical behaviour of the material by examining the complicated impedance data.

## IV. OPTICAL PROPERTIES

The optical properties of metal chalcogenide materials are crucial in determining how they are used in a variety of sectors, such as sensing and optoelectronics. Four key facets of their optical behaviour are examined in detail in this thorough investigation: absorption properties, emission properties, nonlinear optical properties, and optical modulation and switching.

### *A. Absorption Properties*

#### *1) Band Structure and Electronic Transitions*

The electrical band structure of metal chalcogenides is intimately related to their optical absorption characteristics. A variety of electronic transitions, such as direct and indirect bandgaps, are commonly seen in these materials. The bandgap is an important parameter in optical applications because it establishes the energy range of light that can be absorbed.

The kind of chalcogenide and the metal cation have an impact on the band structure in metal chalcogenides. For instance, the unique electronic structures of transition metal chalcogenides such as MoS2 and WSe2 are well-known for producing direct bandgaps in the visible spectrum. For optoelectronic applications like photodetectors and light-emitting devices, this feature is very beneficial.

#### *2) Tunability of Absorption*

Tunability of absorption properties is one of the noteworthy characteristics of metal chalcogenides. This tunability results from these materials' composition, structure, and doping being able to be changed. Through manipulation of these factors, scientists can customise the bandgap to permit light absorption within a more or less restricted range. For example, adjustable bandgap materials can be synthesised by alloying metal chalcogenides or by forming heterostructures with distinct chalcogenides. Designing materials with particular absorption properties for solar cells or other optoelectronic devices depends on this tunability.

### *B. Emission Properties*

#### *1) Photoluminescence and Quantum Yield*

Photoluminescence, in which absorbed photons re-emit at longer wavelengths, is a common phenomenon in metal chalcogenides. The ratio of photons emitted to photons absorbed, or the quantum yield, is used to measure how efficient this process is. Comprehending the behaviour of photoluminescence is crucial for applications involving light-emitting diodes (LEDs) and other similar devices. Surface states, contaminants, and defects can all affect the quantum yield in metal chalcogenides. For instance, photoluminescence in metal sulphide chalcogenides can be enhanced by the presence of sulphur vacancies. Devices that depend on effective light emission can function better when these variables are under control since it makes it possible to optimise quantum yield.

*2) Two-Dimensional Materials and Quantum Confinement*

Two-dimensional (2D) metal chalcogenide materials have become more and more popular recently because of their special optical characteristics brought about by quantum confinement processes. Size-dependent bandgaps in materials like graphene, MoS2, and WS2 allow for variable emission qualities depending on the size of the nanostructures.

To take advantage of quantum confinement phenomena, metal chalcogenide low-dimensional structures such as quantum dots and nanosheets have been synthesised. These materials exhibit potential for use in light-emitting nanodevices and quantum dots for bioimaging.

### *C. Nonlinear Optical Properties*

*1) Nonlinear Absorption and Refraction*

Moreover, metal chalcogenides exhibit fascinating nonlinear optical characteristics such as nonlinear refraction and absorption. Nonlinear refraction is the term used to describe variations in the refractive index with increasing light intensity, whereas nonlinear absorption is the intensity-dependent absorption of light. Applications for metal chalcogenides' nonlinear optical characteristics include ultrafast laser systems and nonlinear optical imaging. These materials are well suited for nonlinear optics, where high-intensity light manipulation is essential, due to their strong light-matter interactions.

*2) Second Harmonic Generation*

A nonlinear optical process known as second harmonic generation (SHG) creates a photon at twice the frequency by combining two photons of the same frequency. Some metal chalcogenides show notable SHG responses, especially those with non-centrosymmetric crystal structures. SHG is used in many different fields, such as bioimaging, telecommunications, and frequency doubling for laser sources. In order to improve SHG efficiency, metal chalcogenides with specific crystal symmetries are useful for developing nonlinear optical technologies.

### *D. Optical Modulation and Switching*

*1) Electrochromism and Photochromism*

Additionally possessing optical modulation characteristics, metal chalcogenides find use in displays and smart windows. When a voltage is supplied, electrochromic materials experience reversible colour or opacity changes. The electrochromic behaviour of transition metal oxides and chalcogenides, including WO3 and MoS2, has been studied. Another optical modulation phenomena are photochromism, in which materials undergo colour or transparency changes in response to light. Ag2S and Ag2Se are two examples of metal chalcogenides that exhibit photochromic behaviour, suggesting use in optical switches and light-sensitive electronics.

*2) Optical Switching in Phase-Change Materials*

Phase-change materials (PCMs) show reversible transitions between amorphous and crystalline phases in response to external stimuli. PCMs are frequently based on chalcogenides such as GeTe and Sb2Te3. This feature is used in optical data storage, where information encoding and retrieval are made possible by variations in optical reflectivity caused by phase transitions.

These materials are suitable for use in reconfigurable photonic devices and non-volatile memory due to their quick and reversible switching.

## V. ELECTRICAL PROPERTIES

The electrical properties of metal chalcogenide materials are fundamental to their utilization in a wide range of electronic devices, including transistors, solar cells, sensors, and thermoelectric devices. Understanding and manipulating these properties are crucial for optimizing the performance of these materials in various applications. This exploration delves into the key electrical properties of metal chalcogenides, covering conductivity, carrier mobility, and their applications in electronic devices.

### *A. Conductivity and Band Structure*

*1) Band Structure and Electronic Conduction*

The electrical conductivity of metal chalcogenides is largely dependent on their electronic band structure. These materials typically show a difference between conduction bands, which contain higher energy electrons, and valence bands, which contain lower energy electrons. The behaviour of a material as an insulator, semiconductor, or metal is determined by the energy gap existing between these bands.

Because they can be made to have a certain bandgap by selecting the right metal cation and chalcogenide anion, metal chalcogenides are frequently classified as semiconductors. Semiconducting materials with tunable bandgaps, like $MoS_2$ and $WSe_2$, are examples of transition metal chalcogenides and are useful for a wide range of electronic applications.

*2) Semiconductor Behaviour and Tunability*

For electronic devices, the semiconductor behaviour of metal chalcogenides is especially useful. Transistors, diodes, and other crucial electronic components can be made possible by the modulation of semiconductors between conducting and insulating states.

Metal chalcogenides can have their bandgaps altered via alloying, doping, and heterostructure formation. Additional charge carriers are introduced through doping with elements of differing valence, which affects the material's electrical conductivity. To customise the electrical characteristics of metal chalcogenides for particular uses, this tunability is necessary.

*B. Doping Effects on Electrical Properties*

*1) N-type and p-type Doping*

One effective method for adjusting the electrical characteristics of metal chalcogenides is doping. One can alter the concentration and kind of charge carriers in a crystal lattice by adding impurities or foreign materials. Depending on the type of dopant used, doping can result in either n-type (additional electrons) or p-type (missing electrons, also referred to as holes) conductivity.

Elemental dopants from adjacent periodic table groups are frequently used in metal chalcogenides. Doping with nitrogen or phosphorus, for instance, can provide more electrons to the system (n-type doping), whereas doping with boron or aluminium can produce holes and improve p-type conductivity.

*2) Influence on Carrier Mobility*

Doping has an impact on charge carrier movement as well as concentration, which is important for electrical conductivity. How quickly charge carriers can travel through a crystal lattice in response to an electric field depends on their mobility.

To maximise the performance of electronic devices, doping-induced modifications in carrier concentration and mobility in metal chalcogenides are crucial. In order to facilitate effective charge transport in transistors and other semiconductor devices, high carrier mobility is preferred. This enhances the material's total electrical conductivity.

*C. Superconductivity*

*1) Transition Metal Chalcogenides and Superconductivity*

Superconductivity, which is defined as the total loss of electrical resistance below a threshold temperature, is a property of several metal chalcogenides. Well-known superconductors, transition metal chalcogenides ($NbSe_2$ and $TaS_2$) have critical temperatures that, depending on the material and structural alterations made to it, can range from a few Kelvins to ambient temperature.

The production of Cooper pairs, in which electrons with opposing spins form pairs and flow through the crystal lattice without scattering, is the source of the superconducting behaviour of metal chalcogenides. This extraordinary characteristic has uses in sensitive magnetometers, magnetic levitation, and energy transfer, among other areas.

*2) High-Temperature Superconductors*

The search for novel metal chalcogenide materials has resulted from the goal of understanding and finding high-temperature superconductors. Practical applications are drawn to copper-based chalcogenides, like $YBa_2Cu_3O_7$, because of their superconductivity at relatively high temperatures. Among other technologies, high-temperature superconductors could transform power transmission and magnetic resonance imaging.

*D. Thermoelectric Properties*

*1) Seeback Effect and Thermoelectric Efficiency*

Metal chalcogenides are useful for turning waste heat into electrical energy because they also exhibit intriguing thermoelectric characteristics. The Seebeck effect is a fundamental phenomenon in thermoelectricity, where a temperature differential across a material produces a voltage. Applications in cooling and power generation are presently being researched for metal chalcogenides with appropriate band structures and high thermoelectric efficiency. The figure of merit (ZT) of a thermoelectric material indicates its efficiency. ZT values are improved and the performance of metal chalcogenides in thermoelectric devices is increased by their advantageous electronic properties, such as high electrical conductivity and low thermal conductivity.

*2) Nanostructuring for Enhanced Thermoelectric Properties*

For metal chalcogenides to have optimal thermoelectric characteristics, nanostructuring is essential. Nanowires, nanosheets, and quantum dots are examples of materials with reduced dimensions that can improve phonon scattering and lower heat conductivity. The material's electrical characteristics are mainly unaltered at the same time, increasing thermoelectric efficiency.

The goal of this research is to create scalable techniques for nanostructuring metal chalcogenides in order to improve their thermoelectric performance. This will open the door to more effective waste heat recovery and energy harvesting devices.

## VI. APPLICATIONS

Metal chalcogenide materials have a wide range of uses in a variety of scientific and technological fields because of their unique and adjustable characteristics. These materials remain essential to the development of technology, being used in everything from electronics to energy storage, sensing, and more. In order to demonstrate the importance of metal chalcogenide materials in influencing contemporary technology, we shall examine a few important uses for them in this investigation.

### *A.* Electronic Devices and Semiconductors

Electronics and semiconductor technology have benefited greatly from the use of metal chalcogenides. They are excellent choices for a range of electrical devices, such as integrated circuits, diodes, and transistors, due to their tunable bandgap and semiconductor behaviour. Due to their two-dimensional structure, transition metal chalcogenides such as MoS2 and WSe2 have drawn special interest for their electrical characteristics. By using these materials, high-performance transistors with lower power consumption can be made, opening the door for electronic devices that use less energy. These materials' scalability is encouraging for the advancement of next-generation nanoelectronics.

### *B.* Photovoltaics and Solar Cells

In the field of photovoltaics, metal chalcogenides are essential because they are used in the production of solar cells. Notable examples of chalcogenides used in thin-film solar cells are copper indium gallium selenide (CIGS) and cadmium telluride (CdTe).

The excellent absorption of sunlight and the production of photo-induced charge carriers are made possible by the semiconducting characteristics of metal chalcogenides in these solar cells. These materials' bandgaps can be tuned, which makes it possible to create solar cells that are tailored for particular sun spectrum areas. Metal chalcogenides help create more affordable and environmentally friendly photovoltaic technology as the need for renewable energy sources grows.

### *C.* Thermoelectric Generators

Metal chalcogenides are useful for use in thermoelectric generators because of their thermoelectric characteristics. These generators use the Seebeck effect, which is the process by which a temperature gradient generates a voltage, to transform waste heat into electrical energy. Power generating thermoelectric modules are designed using specific metal chalcogenides, particularly those with advantageous thermoelectric efficiency. These modules provide a way to capture and use thermal energy that would otherwise be squandered, and they find use in a variety of industries, including industrial operations and automotive systems. These materials' performance in thermoelectric applications can be further improved by adjusting their thermal and electrical conductivity.

### *D. Superconductors and Magnetic Levitation*

Below a specific temperature, certain metal chalcogenides have superconducting qualities, which are defined by total absence of electrical resistance. Superconductors of note include the transition metal chalcogenides NbSe2 and TaS2.

Superconductors are used in many different areas, such as sensitive magnetometers, high-speed maglev (magnetic levitation) transportation systems, and magnetic resonance imaging (MRI) in medical diagnostics. Superconducting metal chalcogenides' exceptional capacity to conduct electricity losslessly creates opportunities for the advancement of cutting-edge technologies that depend on extremely low temperatures and powerful magnetic fields.

### *E. Sensors and Detectors*

Metal chalcogenides are great options for sensors and detectors due to their tunable optical and electrical characteristics. Metal oxide chalcogenides, including SnO2 and ZnO, are frequently employed in gas sensors to identify different types of gases. Additionally, metal chalcogenides are used in optoelectronic sensors, where their radiation and light sensitivity is utilised for devices like photodetectors and imaging systems. These materials' adaptability enables the creation of sensors that are suited to particular gases and situations, which could have uses in industrial safety, environmental monitoring, and medical fields.

### *F. Quantum Technology*

In the field of quantum technologies, certain metal chalcogenides—particularly those in low-dimensional structures like quantum dots and nanowires—display quantum features that are intriguing. Metal chalcogenide-based quantum dots have the potential to function as quantum bits (qubits) in quantum computing, ushering in a new era of information processing with unheard-of computational capacity. Furthermore, the fields of quantum cryptography and quantum communication investigate the quantum characteristics of metal chalcogenides. Secure communication and cutting-edge quantum information processing systems could greatly benefit from the capacity to control and manipulate individual quantum states in these materials.

### *G. Energy Storage Devices*

The development of cutting-edge energy storage technologies like batteries and supercapacitors is aided by metal chalcogenides. High-capacity and high-performance energy storage devices are made possible by the special electrochemical qualities of several metal chalcogenides, which make them appropriate electrode materials.

For instance, the possible application of transition metal chalcogenides, such as MoS2 and WS2, in lithium-ion batteries is being studied. These materials' layered structure offers locations for reversible lithium-ion intercalation, which improves battery performance. Metal chalcogenides also contribute to the development of energy storage solutions by being a part of cutting-edge technologies like solid-state and sodium-ion batteries.

### *H. Transparent Conductive Films*

Metal chalcogenides have demonstrated promise in the creation of transparent conductive films, especially those with a two-dimensional structure. Excellent electrical conductivity and transparency can be achieved in thin films by utilising materials such as graphene, MoS2, and WSe2. These translucent conductive films are used in electronic displays, solar cells, and touchscreens. Metal chalcogenide-based films are intriguing for use in new technologies, such as flexible and wearable electronics, because of their scalability and flexibility.

## VII. CHALLENGES AND FUTURE DIRECTIONS

As the study of metal chalcogenide materials for optical and electrical properties progresses, researchers encounter a variety of problems while forging new paths in fascinating directions. Understanding and overcoming these hurdles is critical for realising the full potential of metal chalcogenides and utilising their unique features in a wide range of applications.

### *A. Challenges*

1) *Synthesis Control and Scalability:* It is still difficult to achieve precise control over the synthesis of metal chalcogenide compounds, particularly at the nanoscale. Achieving consistent size distribution, morphology, and crystallinity is critical for tailoring characteristics. Furthermore, scaling concerns may impede scale manufacture of these materials for commercial use.
2) *Defect Engineering and Stability:* Controlling flaws in metal chalcogenides is crucial for improving their electrical and optical properties. However, achieving defect engineering while preserving material stability requires a precise balance. Identifying and removing flaws, such as vacancies or impurities, while maintaining stability remains a difficulty.
3) *Integration in Hybrid Devices:* Metal chalcogenides must be integrated into hybrid devices while remaining compatible with other materials. Creating a seamless interface between metal chalcogenides and other components, such as organic polymers or metal oxides, is a challenge for improving performance and functionality.
4) *Bandgap Engineering Precision:* While bandgap engineering is a useful technique, precise control over the bandgap in metal chalcogenides remains difficult. Alloying, doping, and nanostructuring all have an impact on the bandgap, but fine-tuned control is required to tailor materials to specific applications.
5) *Environmental Impact and Toxicity:* Some metal chalcogenides, such as sulphides and selenides, may contain constituents that pose environmental and health risks. Addressing these materials' environmental effect and toxicity is critical to ensure their safe and long-term use in a variety of applications, particularly in new technologies.
6) *Thermal Management:* Metal chalcogenides are exposed to fluctuating temperatures in a variety of applications, including solar cells and electronics. Improving thermal stability and tackling thermal management difficulties are critical for achieving consistent performance and dependability throughout a wide temperature range.

*B. Future Directions*

1) *Advanced Synthesis Techniques:* Future research should concentrate on developing new synthesis methods that provide fine control over the size, shape, and composition of metal chalcogenides. Advanced templating, solvothermal techniques, and novel approaches such as microwave-assisted synthesis show potential for improving synthesis control.
2) *Defect Engineering Strategies:* Novel defect engineering strategies, such as controlled introduction of specific faults for specified functionalities, will be critical. Understanding the impact of flaws on optical and electrical properties, as well as devising techniques to capitalise on their influence, would open up new possibilities for designing materials for a wide range of applications.
3) *Tailored Bandgap Engineering:* Future study should focus on more refined and tailored bandgap engineering in metal chalcogenides. This includes investigating novel alloying procedures, precision doping strategies, and revolutionary nanostructuring technologies to produce materials with precisely tailored optical and electrical properties for specific applications.
4) *Environmental Sustainability:* To address environmental problems, researchers should investigate the use of eco-friendly precursors and sustainable synthesis techniques. Metal chalcogenides should be recycled and upcycled to reduce their environmental impact and contribute to the development of green technology.
5) *Integration in Multifunctional Devices:* The future offers promising opportunities for incorporating metal chalcogenides into multifunctional devices that combine optical and electrical functions. Researchers can investigate novel designs and hybrid systems that take advantage of the properties of metal chalcogenides in applications ranging from sophisticated sensors to integrated photonics.
6) *Emerging Applications of Quantum Technologies:* Metal chalcogenides have unusual features, particularly at the nanoscale, that make them intriguing candidates for use in quantum technologies. Exploring their potential in quantum information processing, quantum computing, and quantum communication can lead to significant advances in these new domains.
7) *Thermal Management Innovations:* Addressing thermal management difficulties is critical to the effective use of metal chalcogenides in electrical and energy devices. Future study should look into novel thermal management solutions, such as the creation of improved nanocomposites or materials with high thermal conductivity.
8) *Exploration of two-dimensional materials and heterostructures:* The study of two-dimensional (2D) materials, such as graphene and transition metal dichalcogenides, has received considerable attention. Future study can investigate the incorporation of metal chalcogenides into 2D materials and heterostructures, revealing synergistic features and enabling the development of innovative electrical and optoelectronic devices.

## VIII. CONCLUSION

Exploring the optical and electrical properties of metal chalcogenide materials opens up a huge field of possibilities. From synthesis labs to the forefront of electronic device applications and beyond, researchers are navigating a road distinguished by obstacles, breakthroughs, and intriguing future prospects. The optical properties of metal chalcogenides, which include band gap investigations, optical absorption and reflection, and photoluminescence behaviour, reveal the rich tapestry of their interaction with light. Researchers investigate the complexities of electronic transitions, vibrational modes, and luminous behaviours, creating the groundwork for applications in optoelectronics, sensing, and photonics. Simultaneously, the electrical properties of metal chalcogenides, which include conductivity, carrier mobility, and applicability in electronic devices, highlight their importance in the field of semiconductor materials. Challenges such as synthesis control, defect engineering precision, and environmental considerations open the way for future research focused at improving synthesis processes, experimenting with novel defect engineering methodologies, and encouraging sustainability. As we work through the hurdles, the synthesis and preparation procedures become important chapters in the metal chalcogenide story. From controlled nanostructures to targeted flaw engineering, researchers use a wide range of approaches to shape materials with desired optical and electrical properties. The synthesis landscape is poised to evolve, with a focus on scalability, precision, and environmental sensitivity. Characterization techniques, such as X-ray diffraction, scanning electron microscopy, and advanced optical and electrical characterization methods, work as a compass, directing researchers through the maze of material properties. These techniques give the key insights required to unlock the mysteries of metal chalcogenides and customise their properties to specific applications.

In their pursuit of perfection, researchers face hurdles such as temperature control, integration into hybrid systems, and the painstaking tailoring of band gaps. However, these limitations present potential for creativity, sustainability, and the rise of metal chalcogenides as leaders in quantum technologies and multifunctional devices.

As we complete this investigation, the horizon of metal chalcogenide materials beckons with promise. Challenges are not impediments, but rather stepping stones, encouraging researchers to push the limits of synthesis precision, defect engineering skill, and environmental responsibility. The future promises not only improved materials, but also dramatic effects on electronic gadgets, renewable energy, and burgeoning sectors such as quantum technologies.

Metal chalcogenides contribute a unique note to the symphony of science and technology, combining optical splendour with electrical prowess. The story is still developing, with researchers preparing to write the following chapters, which will determine the fate of metal chalcogenide materials in the ever-changing world of materials science.